

Title (en)

Method and circuit for controlling baseband gain

Title (de)

Verfahren und Schaltung zur Steuerung der Basisbandverstärkung

Title (fr)

Procédé et circuit pour contrôler le gain de bande de base

Publication

**EP 2071720 A1 20090617 (EN)**

Application

**EP 09152894 A 20010905**

Priority

- EP 01121259 A 20010905
- JP 2000278334 A 20000913

Abstract (en)

An object of the present invention is to suppress the generation of a transient voltage in the settings of gains of a plurality of series-connected variable gain amplifiers of a baseband circuit. To achieve this object, the present invention provides a gain control method and a baseband amplifier wherein, if the total amplifying gain is to be increased, the gains of the variable gain amplifiers are sequentially increased starting at a variable gain amplifier close to an input of the baseband amplifier, and, if the total amplifying gain is to be decreased, the gains of variable gain amplifiers are sequentially decreased starting at a variable gain amplifier farthest to the input.

IPC 8 full level

**H03G 3/10** (2006.01); **H03G 3/30** (2006.01); **H03G 1/00** (2006.01); **H03G 3/00** (2006.01); **H03G 3/20** (2006.01)

CPC (source: EP KR US)

**H03G 1/0088** (2013.01 - EP US); **H03G 3/00** (2013.01 - KR); **H03G 3/3068** (2013.01 - EP US)

Citation (search report)

- [X] EP 0797299 A2 19970924 - NEC CORP [JP]
- [X] EP 0773625 A1 19970514 - NEC CORP [JP]
- [A] EP 0977354 A1 20000202 - NIPPON TELEGRAPH & TELEPHONE [JP]
- [A] US 5604460 A 19970218 - SEHRIG PETER [DE], et al
- [A] US 5298868 A 19940329 - NAGANO YOSHIKI [JP]
- [A] US 6006079 A 19991221 - JAFFEE JAMES I [US], et al

Citation (examination)

US 5023569 A 19910611 - RAVEN GREGORY S [US]

Designated contracting state (EPC)

DE FR GB IT

DOCDB simple family (publication)

**EP 1191686 A2 20020327**; **EP 1191686 A3 20040901**; **EP 1191686 B1 20140514**; CN 1168206 C 20040922; CN 1344062 A 20020410; EP 2071720 A1 20090617; JP 2002094344 A 20020329; JP 3479835 B2 20031215; KR 100462428 B1 20041217; KR 20020021075 A 20020318; US 2002047744 A1 20020425; US 6480063 B2 20021112

DOCDB simple family (application)

**EP 01121259 A 20010905**; CN 01142128 A 20010913; EP 09152894 A 20010905; JP 2000278334 A 20000913; KR 20010056476 A 20010913; US 95075101 A 20010913